



PRODUCT BULLETIN
Generic Copy

05-AUG-2005

SUBJECT: ON Semiconductor Product Bulletin #14298

TITLE: Datasheet Ir Limit Change for MBRS3200T3/G, MBRS3201T3/G, & MBRS4201T3/G

EFFECTIVE DATE: 05-AUG-2005

AFFECTED PRODUCT DIVISION: Discrete Products

FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor sales office or Louis Tsai <ffnt6m@onsemi.com>

NOTIFICATION TYPE:

ON Semiconductor considers this change approved unless specific conditions of acceptance are provided in writing. To do so, contact your local ON Semiconductor sales office.

DESCRIPTION AND PURPOSE:

This is to inform customers that ON Semiconductor will be correcting the datasheet limit for the room temperature leakage parameter (Ir) for MBRS3200T3/G, MBRS3201T3/G, and MBRS4201T3/G devices.

The current Ir limit does not meet the ON Semiconductor internal qualification requirements, and we will be revising the Ir limit at room temperature to 1mA. With this change in the datasheet, the electrical performance of these devices will remain unchanged.



AFFECTED DEVICE LIST (WITHOUT SPECIALS)

PART

MBS3200T3
MBS3200T3G
MBS3201T3
MBS3201T3G
MBS4201T3
MBS4201T3G